



## ■ Absolute Maximum Ratings

Characteristic	Symbol	Ratings	Unit
Power Dissipation	$P_D$	75	mW
Forward Current	$I_F$	30	mA
* <sup>1</sup> Peak Forward Current	$I_{FP}$	100	mA
Reverse Voltage	$V_R$	5	V
Operating Temperature	$T_{opr}$	-30 ~ +85	°C
Storage Temperature	$T_{stg}$	-40 ~ +100	°C
* <sup>2</sup> Soldering Temperature	$T_{sol}$	260°C for 3 seconds	

\*1. Duty ratio = 1/10, Pulse width = 0.1ms

\*2. Keep the distance more than 2.0mm from PCB to the bottom of LED package

## ■ Electrical – Optical Characteristics

(Ta=25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Forward Voltage	$V_F$	$I_F = 20\text{mA}$	-	2.0	2.7	V
Dominant Wavelength	$\lambda_D$	$I_F = 20\text{mA}$	-	624	-	nm
Spectrum Bandwidth	$\Delta\lambda$	$I_F = 20\text{mA}$	-	15	-	nm
Reverse Current	$I_R$	$V_R = 5\text{V}$	-	-	10	uA
* <sup>3</sup> Half Angle	$\theta_{1/2}$	$I_F = 20\text{mA}$	-	$\pm 10$	-	deg

\*3.  $\theta_{1/2}$  is the off-axis angle where the luminous intensity is 1/2 the peak intensity

## ■ Luminous intensity ranks

(Ta=25°C)

Iv RANK	Test Condition	Min.	Typ.	Max.	Unit
R	I <sub>F</sub> = 20mA	2400	-	3400	mcd
S		3400	-	4800	
T		4800	-	6700	

\* Luminous intensity is tested at a current pulse duration of 25 ms and an accuracy of  $\pm 11\%$ .

\* Intensity Measured : 0.01sr(CIE. LED\_B)

## ■ Precautions On LED using

\* To avoid optical difference, Please do not mix differently-ranked product.

## ■ Characteristic Diagrams

Fig. 1  $I_F$ - $V_F$

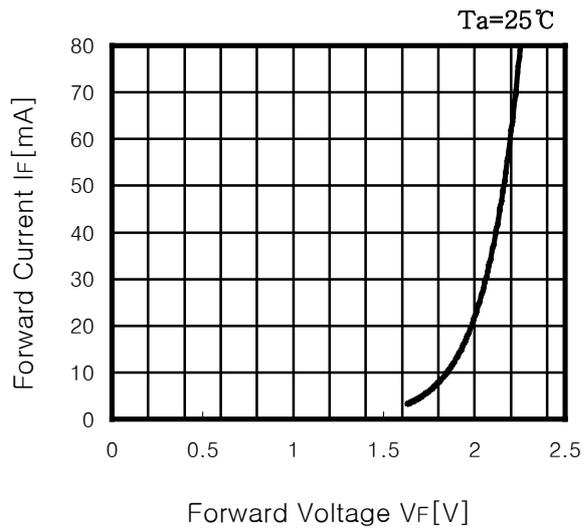


Fig. 2  $I_V$ - $I_F$

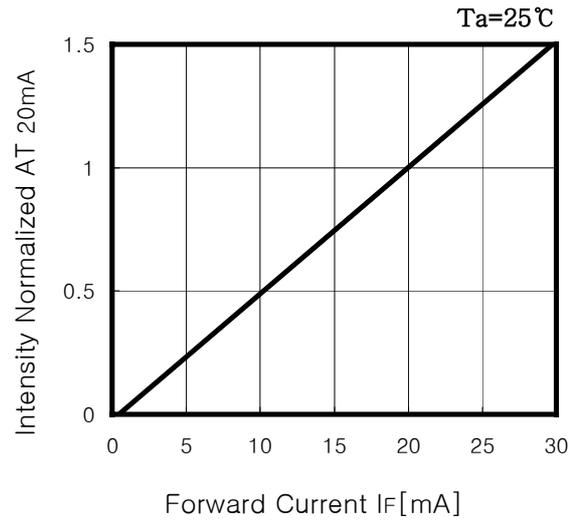


Fig. 3 Spectrum Distribution

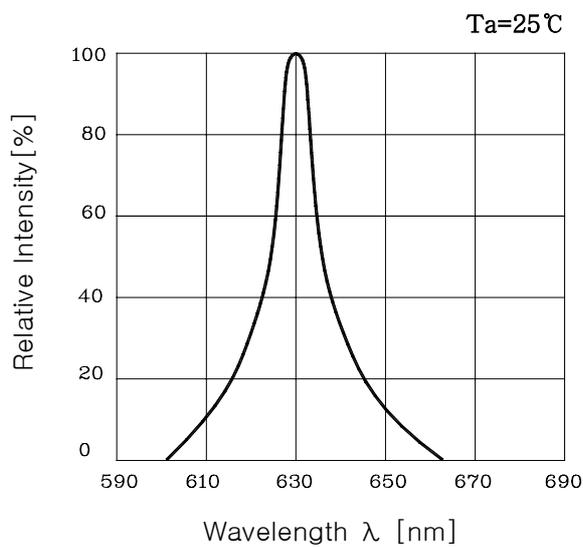


Fig. 4 Relative Intensity- $T_a$

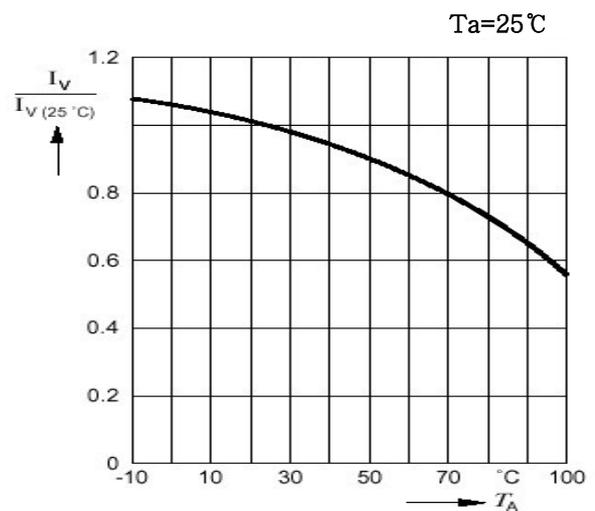
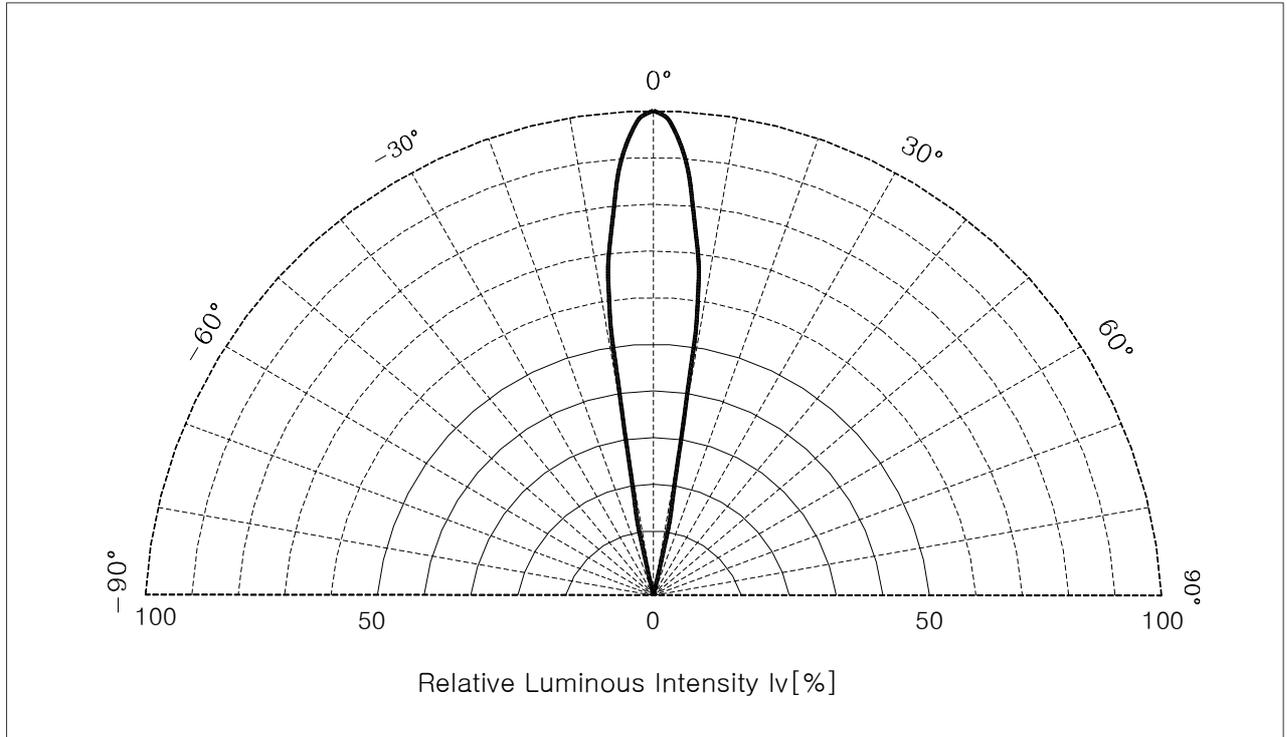


Fig. 5 Radiation Diagram



■ Revision history sheet

Spec NO.			
Title	Specification for Approval		
Times	Date	Summary of revision	Remarks
1	2001. 07. 15	신규제정	
2	2003. 02. 26	Format 변경	